General Purpose Transistors

NPN Silicon

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	32	Vdc
Collector-Base Voltage	V _{CBO}	32	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector Current – Continuous	Ι _C	100	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Total Device Dissipation FR-5 Board ⁽¹⁾ $T_A = 25^{\circ}C$	PD	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	556	°C/W
Total Device Dissipation Alumina Substrate, ⁽²⁾ $T_A = 25^{\circ}C$	P _D	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

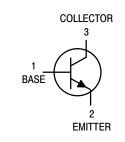
1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = 0.4 \times 0.3 \times 0.024 in. 99.5% alumina.



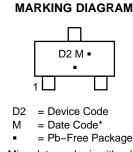
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SOT-23 (TO-236) CASE 318 STYLE 6



(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
BCW32LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel
NSVBCW32LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

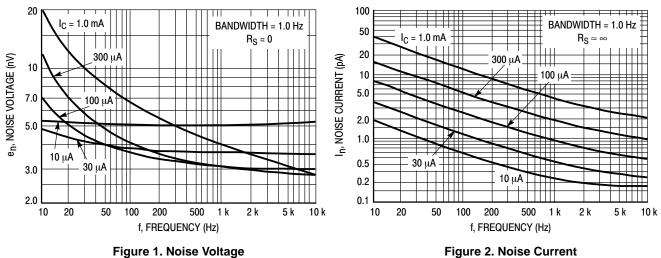
	,				
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	·				
Collector – Emitter Breakdown Voltage ($I_C = 2.0 \text{ mAdc}, V_{EB} = 0$)	V _{(BR)CEO}	32	-	-	Vdc
Collector – Base Breakdown Voltage $(I_C = 10 \ \mu Adc, I_E = 0)$	V _{(BR)CBO}	32	-	-	Vdc
Emitter-Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	V _{(BR)EBO}	5.0	_	-	Vdc
Collector Cutoff Current $(V_{CB} = 32 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 32 \text{ Vdc}, I_E = 0, T_A = 100^{\circ}\text{C})$	I _{CBO}			100 10	nAdc μAdc
ON CHARACTERISTICS					-
DC Current Gain (I _C = 2.0 mAdc, V _{CE} = 5.0 Vdc)	h _{FE}	200	_	450	_
Collector – Emitter Saturation Voltage	Vorum	1			Vdc

$(12 - 2.0 \text{ mAd}), V_{\text{E}} = 0.0 \text{ Vd})$		200	_	400	
Collector – Emitter Saturation Voltage $(I_C = 10 \text{ mAdc}, I_B = 0.5 \text{ mAdc})$	V _{CE(sat)}	-	-	0.25	Vdc
Base-Emitter On Voltage (I _C = 2.0 mAdc, V _{CE} = 5.0 Vdc)	V _{BE(on)}	0.55	-	0.70	Vdc

SMALL-SIGNAL CHARACTERISTICS

Output Capacitance ($I_E = 0$, $V_{CB} = 10$ Vdc, f = 1.0 MHz)	C _{obo}	-	-	4.0	pF
Noise Figure (I _C = 0.2 mAdc, V _{CE} = 5.0 Vdc, R _S = 2.0 k Ω , f = 1.0 kHz, BW = 200 Hz)	NF	-	-	10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



TYPICAL NOISE CHARACTERISTICS $(V_{CE}=5.0~Vdc,~T_{A}=25^{\circ}C)$

Figure 2. Noise Current

NOISE FIGURE CONTOURS

 $(V_{CE}=5.0~Vdc,~T_{A}=25^{\circ}C)$

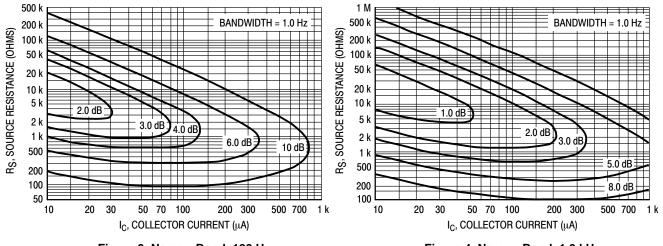
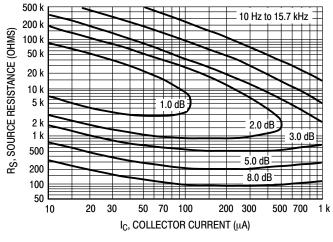
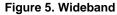


Figure 3. Narrow Band, 100 Hz







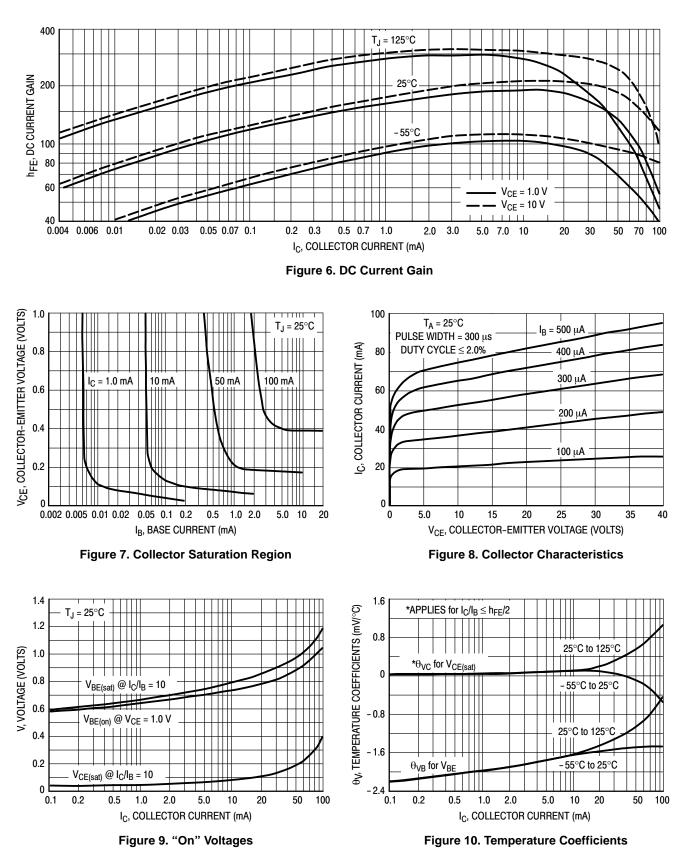
Noise Figure is defined as:

$$NF = 20 \log_{10} \left(\frac{e_{n}^{2} + 4KTR_{S} + I_{n}^{2}R_{S}^{2}}{4KTR_{S}} \right)^{1/2}$$

 e_n = Noise Voltage of the Transistor referred to the input. (Figure 3) I = Noise Current of the Transistor referred to the input. _n (Figure 4)

- $K = Boltzman's Constant (1.38 x 10^{-23} j/°K)$
- T = Temperature of the Source Resistance ($^{\circ}$ K)
- R = Source Resistance (Ω)
- S

TYPICAL STATIC CHARACTERISTICS



TYPICAL DYNAMIC CHARACTERISTICS

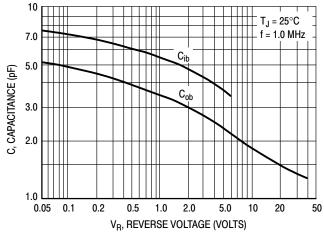


Figure 11. Capacitance





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